

A first-principles study on nonmetal and nonmagnetic metal atoms doped arsenene

M. Luo⁺¹⁾, Y. E. Xu*, Y. X. Song[×]

⁺Department of Physics, Shanghai Second Polytechnic University, Shanghai 201209, China

^{*}Department of Electronic Engineering, Shanghai Jian Qiao University, Shanghai 201306, China

[×]Key Laboratory of Polar Materials and Devices, East China Normal University, Shanghai 200241, China

Submitted 4 August 2017

DOI: 10.7868/S0370274X17190043

Recently, a new elemental 2D material has been identified based on theoretical calculations, namely grey arsenic, which is the structural counterpart of blue phosphorus. It can transform into an indirect band-gap semiconductor as thin as a monolayer (arsenene), which is different from planar graphene, silicene and puckered phosphorene. Interestingly, it can transform from indirect gap to direct gap semiconductor under biaxial strain and gets lots of attention. It has been verified that magnetism induced by the *sp* states of nonmetal elements has much stronger long-range exchange coupling interactions without clustering of magnetic ions. Therefore, we investigate the electronic and magnetic properties of *X*-doped arsenenes (*X*=B, C, F, N, O, Al, Ga, Li, Mg, and Na), as shown in Fig. 1a, using first-principles method. Magnetic states are observed in the case of C. According to the binding energy, the C-doped arsenene is the most stable system, as shown in Fig. 1b. Then, we investigate the interaction between two C dopants and both nonmagnetic (NM) and anti-ferromagnetic (AFM) states were found. The projected density of states shows that the AFM order could be explained by the *p*–*p* coupling between C and its neighboring As atoms, as shown in Fig. 1c. Our study suggests that nonmetal dopant might be a possible approach to tune electronic and magnetic properties of arsenene [1–25].

Full text of the paper is published in JETP Letters journal. DOI: 10.1134/S0021364017190018

1. K. S. Novoselov, A. K. Geim, S. V. Morozov, D. Jiang, Y. Zhang, S. V. Dubonos, I. V. Grigorieva, and A. A. Firsov, *Science* **306**, 666 (2004).
2. A. K. Geim and K. S. Novoselov, *Nature Mater.* **6**, 183 (2007).
3. A. H. Castro Neto, F. Guinea, N. M. R. Peres, K. S. Novoselov, and A. K. Geim, *Rev. Mod. Phys.* **81**, 109 (2009).
4. K. F. Mak, C. Lee, J. Hone, J. Shan, and T. F. Heinz, *Phys. Rev. Lett.* **105**, 136805 (2010).
5. B. Radisavljevic, A. Radenovic, J. Brivio, V. Giacometti, and A. Kis, *Nature Nanotech.* **6**, 147 (2011).
6. S. Rodin, A. Carvalho, and A. H. Castro Neto, *Phys. Rev. Lett.* **112**, 176801 (2014).
7. T. Low, A. S. Rodin, A. Carvalho, Y. Jiang, H. Wang, F. Xia, and A. H. Castro Neto, *Phys. Rev. B* **90**, 075434 (2014).
8. R. Fei, A. Faghaninia, R. Soklaski, J. A. Yan, C. Lo, and L. Yang, *Nano Lett.* **14**, 6393 (2014).
9. A. Ramasubramaniam and A. R. Muniz, *Phys. Rev. B* **90**, 085424 (2014).
10. J. C. S. Levy, *J. Magn. Magn. Mater.* **373**, 2 (2015).
11. C. Kamal and M. Ezawa, *Phys. Rev. B* **91**, 085423 (2015).
12. L. Kou, Y. Ma, X. Tan, T. Frauenheim, A. Du, and S. Smith, *J. Phys. Chem. C* **119**, 6918 (2015).
13. S. L. Zhang, Z. Yan, Y. F. Li, Z. F. Chen, and H. B. Zeng, *Angew. Chem. Int. Ed.* **54**, 3112 (2015).
14. D. C. Wang, L. Chen, C. M. Shi, X. L. Wang, G. L. Cui, P. H. Zhang, and Y. Q. Chen, *Sci. Rep.* **6**, 28487 (2016).
15. F. Ersan, E. Aktürk, and S. Ciraci, *J. Phys. Chem. C* **120**, 14345 (2016).
16. A. Hashmi and J. Hong, *J. Phys. Chem. C* **119**, 9198 (2015).
17. O. V. Yazyev and L. Helm, *Phys. Rev. B* **75**, 125408 (2007).
18. L. Shen, R. Q. Wu, H. Pan, G. W. Peng, M. Yang, Z. D. Sha, and Y. P. Feng, *Phys. Rev. B* **78**, 073306 (2008).
19. J. J. Attema, G. A. de Wijs, G. R. Blake, and R. A. de Groot, *J. Am. Chem. Soc.* **127**, 16325 (2005).
20. J. P. Perdew, K. Burke, and M. Ernzerhof, *Phys. Rev. Lett.* **77**, 3865 (1996).

¹⁾e-mail: luomin@sspu.edu.cn

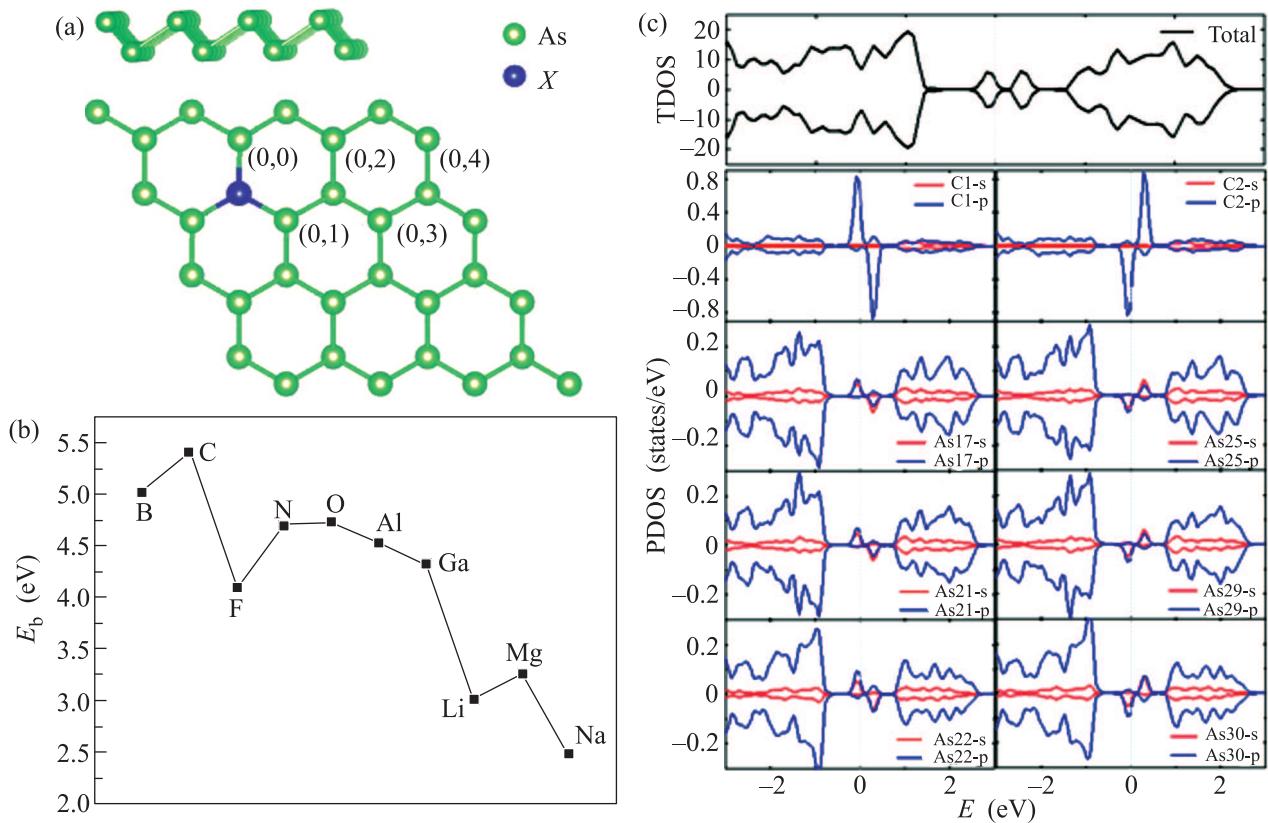


Fig. 1. (Color online) (a) – Top view of X -doped $4 \times 4 \times 1$ arsenene ($X = \text{B}, \text{C}, \text{F}, \text{N}, \text{O}, \text{Al}, \text{Ga}, \text{Li}, \text{Mg}$, and Na). (b) – Binding energies of different nonmetals and nonmagnetic metals doped in the $4 \times 4 \times 1$ $\text{As}X$, (c) – PDOS of two-C-doped system [case (0,4)]. The ground state is AFM

21. G. Kresse and J. Furthmüller, Phys. Rev. B **54**, 11169 (1996).
22. G. Kresse and D. Joubert, Phys. Rev. B **59**, 1758 (1999).
23. P. Wu, M. Huang, W. J. Cheng, and F. L. Tang, Physica E **81**, 7 (2016).
24. L. Kou, Y. Ma, X. Tan, T. Frauenheim, A. Du, and S. Smith, J. Phys. Chem. C **119**, 6918 (2015).
25. P. Dev and P. H. Zhang, Phys. Rev. B: Condens. Matter Mater. Phys. **81**, 085207 (2010).